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|--|---|---|---|
| K-No.: 26810 | 15A Current Sensor For the electronic measurement of currents: DC, AC, pulsed, mixed with a galvanic Isolation between the primary circuit (high power) and the secondary circuit (electronic circuit) |  | Date: 26.07.2017 |
| Customer: Standard Type | | Customers Part no: | Page 1 of 3 |
| Description <ul style="list-style-type: none"> Closed loop (compensation) Current Sensor with magnetic probe Printed circuit board mounting Casing and materials UL-listed | | Characteristics <ul style="list-style-type: none"> excellent accuracy very low offset current very low temperature dependency and offset current drift very low hysteresis of offset current short response time wide frequency bandwidth compact design reduced offset ripple | Applications <p>Mainly used for stationary operation in industrial applications:</p> <ul style="list-style-type: none"> AC variable speed drives and servo motor drives static converters for DC motor drives Battery supplied applications Switched Mode Power Supplies (SMPS) Power supplies for welding applications Uninterruptable Power Supplies (UPS) |

Electrical data - Ratings

| | | | |
|------------------|---|---|---|
| I _{PN} | Primary nominal RMS current | 15 | A |
| V _{OUT} | Output voltage @ I _P | V _{REF} ± (0.625*I _P /I _{PN}) | V |
| V _{OUT} | Output voltage @ I _P =0A, θ _A =25°C | V _{REF} ± 0.00221 | V |
| V _{REF} | External Reference voltage range | 0 ... 4 | V |
| | Internal Reference voltage | 2.5 ± 0.005 | V |
| K _N | Transformation ratio | 1...3 : 2000 | |

Accuracy – Dynamic performance data

| | | min. | typ. | max. | Unit |
|---------------------------------------|--|----------|-------|------|--------|
| I _{P,max} | Max. measuring range | ±51 | | | A |
| X | Accuracy @ I _{PN} , θ _A = 25°C | | 0.7 | | % |
| ε _L | Linearity | | 0.1 | | % |
| V _{OUT} -V _{REF} | Offset voltage @ I _P = 0A, θ _A = 25°C | | ±2.21 | | mV |
| ΔV _O /V _{REF} /Δθ | Temperature drift of V _{OUT} @ I _P =0A, V _{REF} =2.5V, θ _A | 2.3 | 20 | | ppm/°C |
| t _r | Response time | | 0.3 | | μs |
| t _{ra} | Reaction time at di/dt = 100 A/μs | | 0.2 | | μs |
| f | Frequency bandwidth | DC...200 | | | kHz |

General data

| | | | | |
|----------------|--|------|----|------|
| θ _A | Ambient operation temperature | -40 | 85 | °C |
| θ _S | Ambient storage temperature | -40 | 85 | °C |
| m | Mass | 12 | | g |
| V _C | Supply voltage | 4.75 | 5 | 5.25 |
| I _c | Supply current at I _P = 0A and RT | 15 | | mA |

| | | | | |
|----------------------------------|---|------|--|-------------------|
| ¹⁾ S _{clear} | Clearance (component without solder pad) | 7.4 | | mm |
| ¹⁾ S _{creep} | Creepage (component without solder pad) | 8.0 | | mm |
| ¹⁾ U _{sys} | System voltage *overvoltage category 3 | 300 | | V _{RMS} |
| ¹⁾ U _{AC} | Working voltage *acc. table 7, overvoltage category 2 | 650 | | V _{RMS} |
| ¹⁾ U _{PD} | Rated discharge voltage | 1320 | | V _{PEAK} |

According to UL 508: max. potential difference 600 V_{AC}

¹⁾Constructed and manufactured and tested in accordance with EN 61800-5-1:2003 (primary to secondary)
Reinforced insulation, Insulation material group 1, Pollution degree 2

The current sensor passed the EMI susceptibility tests (vertical and horizontal, one direction) according to the standard 61000-4-3:2010 at 20V/m, 80%AM@1kHz over the frequency range of 80MHz to 1000MHz, level a) with <2% variation of the Vout during the stress.

| | | | |
|-------------------------|---------------------|-----------------|----------------------|
| Date | Name | Issue | Amendment |
| | | 81 | |
| Hrg.: R&D-PD NPI editor | Bearb.: DJ designer | MC-PM: Su check | freig.: BEF released |

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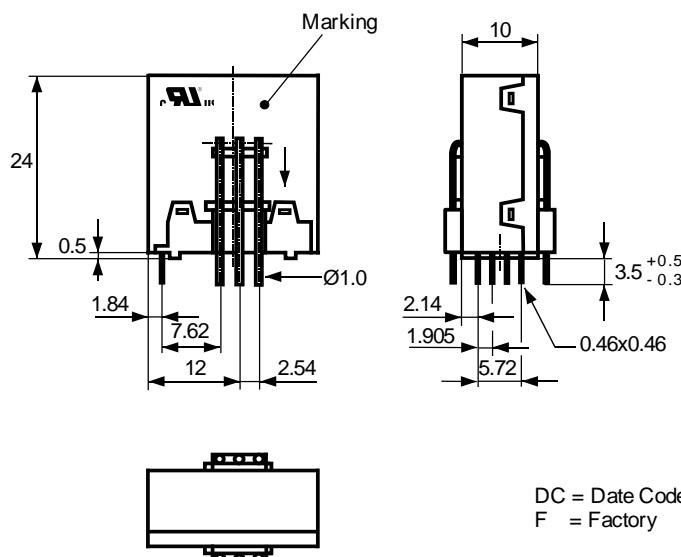
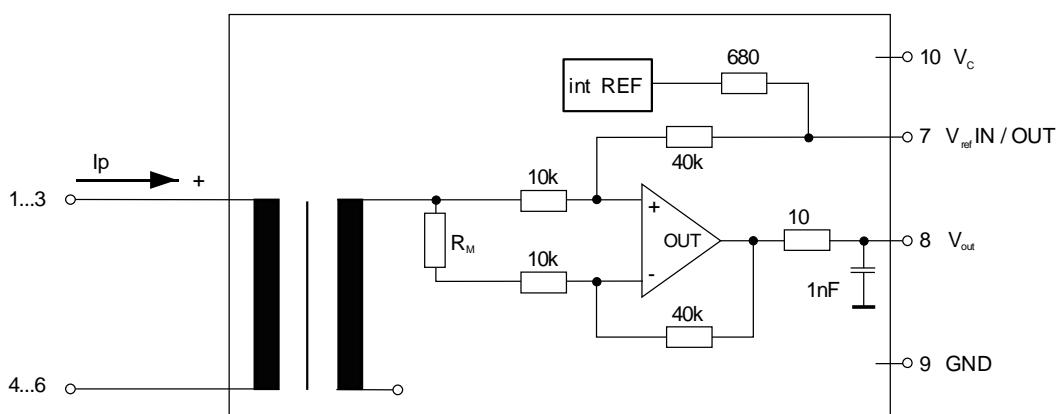

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| <u>Mechanical outline (mm):</u> | | General tolerances DIN ISO 2768-C | Connections: |
|---------------------------------|---|-------------------------------------|--|
| 6 | 4 | Tolerances grid distance ±0.2 mm | Pin Nr. 1-6: Ø1mm Pin Nr. 7-10: 0.46 x 0.46mm |


Schematic diagram:

Hrg.: R&D-PD NPI
editor

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| Electrical data: (investigate by a type checking) | | min. | typ. | max. | Unit |
|--|--|------|--------------------------------------|------|-----------|
| $V_{C,tot}$ | maximum supply voltage (without function) | | 7 | | V |
| I_C | Supply Current with primary current | | $15mA + I_p \cdot K_N + V_{OUT}/R_L$ | | mA |
| $I_{OUT,SC}$ | Short circuit output current | | ± 20 | | mA |
| R_P | Resistance per primary winding @ $\vartheta_A=25^\circ C$ | | 1 | | $m\Omega$ |
| R_S | Secondary coil resistance @ $\vartheta_A = 85^\circ C$ | | | 67 | Ω |
| $R_{i,REF}$ | Internal resistance of Reference output | | 680 | | Ω |
| $R_{i,Vout}$ | Output resistance of V_{OUT} | | 10 | | Ω |
| R_L | External recommended resistance of V_{OUT} | 1 | | | $k\Omega$ |
| C_L | External recommended capacitance of V_{OUT} | | 1 | | nF |
| $X_{Ti} / \Delta\vartheta$ | Temperature drift of X @ $\vartheta_A = -40^\circ C \dots 85^\circ C$ | | 40 | | ppm/K |
| $\Delta V_O = \Delta(V_{OUT} - V_{REF})$ | Sum of any offset drift including: | | 3.5 | 10 | mV |
| V_{Ot} | Long term drift of V_O | 2 | | | mV |
| V_{OT} | Temperature drift of V_O @ $\vartheta_A = -40^\circ C \dots 85^\circ C$ | 2 | | | mV |
| V_{OH} | Hysteresis of V_{OUT} @ $I_p=0A$ (caused by $I_p = 10 \times I_{PN}$) | | 3 | | mV |
| $\Delta V_O / \Delta V_C$ | Supply voltage rejection ratio | | 1 | | mV/V |
| Voss | Offsetripple (with 1 MHz-Filter, first order) | | 30 | | mV_{PP} |
| Voss | Offsetripple (with 100 kHz-Filter, first order) | 6 | 10 | | mV_{PP} |
| Voss | Offsetripple (with 20 kHz-Filter, first order) | 4 | 7 | | mV_{PP} |
| C_k | Maximum possible coupling capacity (primary - secondary) | | 5 | | pF |
| | Mechanical stress according to M3209/3 Settings: 10-2000Hz, 1min/oct, 2 hours | | | 30 | g |

Routine-Tests: (Measurement after temperature balance of the samples at room temperature, SC=significant characteristic)

| | | | | |
|-------------------|-------------------|--|-----------------|------------|
| V_{OUT} (SC) | (100%) M3011/6: | Output voltage | $625 \pm 0.7\%$ | mV |
| $V_{OUT}-V_{REF}$ | (100%) M3226: | Offset voltage | ± 2.21 | mV |
| U_d | (100%) M3014: | Test voltage, 1s | 1.5 | kV_{RMS} |
| U_{PDE} | (AQL 1/S4) M3024: | Partial discharge voltage (extinction) | 1.4 | kV_{RMS} |
| $U_{PD}^* 1.875$ | | | 1.75 | |

Type-Tests: (Precondition acc. to M3236)

| | | | |
|------------------|--|------|------------|
| \hat{U}_W | HV transient test acc. to M3064 (1.2 μs / 50 μs -Waveform) | 6 | kV |
| U_d | Test voltage acc. to M3014 | (5s) | 3 |
| U_{PDE} | Partial discharge voltage (extinction) | 1.4 | |
| $U_{PD}^* 1.875$ | acc. to M3024 | 1.75 | kV_{RMS} |

Other instructions:

- Current direction: A positive output voltage vs. V_{REF} appears at point V_{OUT} , if primary current flows in direction of the arrow sign on Sensor package.
- Constructed, manufactured and tested in accordance with IEC 61800-5-1:2007
- Temperature of the primary conductor should not exceed 105°C.
- Housing and bobbin material UL-listed: Flammability class 94V-0.

Hrg.: R&D-PD NPI
editorBearb.: DJ
designerMC-PM: Su
checkfreig.: BEF
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